

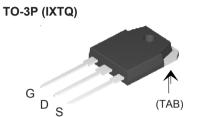
## PolarHV<sup>™</sup> Power MOSFET

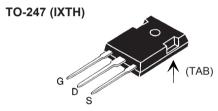
N-Channel Enhancement Mode Avalanche Rated IXTH 36N50P IXTQ 36N50P IXTT 36N50P IXTV 36N50PS  $V_{DSS} = 500 V \ I_{D25} = 36 A \ R_{DS(on)} \le 170 m\Omega$ 



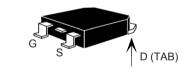
		03			
Symbol	Test Conditions	Maximum	Ratings		
V <sub>DSS</sub> V <sub>DGR</sub>	$T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}$ $T_J = 25^{\circ} \text{ C to } 150^{\circ} \text{ C}; R_{GS} = 1 \text{ M}\Omega$	500 500	V		
V <sub>GS</sub>	Continuous	±30	V		
$V_{\rm GSM}$	Transient	±40	V		
I <sub>D25</sub>	$T_{\rm c}^{}=25^{\circ}{\rm C}$ $T_{\rm c}^{}=25^{\circ}{\rm C}$ , pulse width limited by $T_{\rm JM}^{}$	36 108	A A		
I <sub>AR</sub> E <sub>AR</sub> E <sub>AS</sub>	T <sub>c</sub> = 25° C T <sub>c</sub> = 25° C T <sub>c</sub> = 25° C	36 50 1.5	A mJ J		
dv/dt	$I_{_{S}} \leq I_{_{DM}}, \text{ di/dt} \leq 100 \text{ A/}\mu\text{s}, V_{_{DD}} \leq V_{_{DSS}}, \\ T_{_{J}} \leq 150^{\circ}\text{ C}, R_{_{G}} = 3 \Omega$	10	V/ns		
$P_{D}$	T <sub>C</sub> =25°C	540	W		
T <sub>J</sub> T <sub>JM</sub> T <sub>stg</sub>		-55 +150 150 -55 +150	°C °C °C		
T <sub>L</sub> T <sub>SOLD</sub>	1.6 mm (0.062 in.) from case for 10 s Plastic body for 10 s	300 260	°C °C		
M <sub>d</sub>	Mounting torque(TO-247)	1.13/10	Nm/lb.in.		
F <sub>c</sub>	Mounting force (PLUS220)	20120/4.515	N/lb		
Weight	TO-247 TO-268 PLUS220 TO-3P	6 5 2 5.5	g g g		

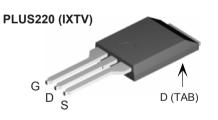
<b>Symbol</b> (T <sub>J</sub> = 25° C u	Test Conditions nless otherwise specified)		Ch Min.	istic Val   Max.	
V <sub>DSS</sub>	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$		500		V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_{D} = 250 \mu A$		3.0	5.0	V
I <sub>GSS</sub>	$V_{GS} = \pm 30 \ V_{DC}, \ V_{DS} = 0$			±100	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T <sub>J</sub> = 125° C		25 250	μA μA
R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_{D} = 0.5 I_{D25}$ Pulse test, t \le 300 \mus, duty (	cycle d ≤ 2 %		170	mΩ



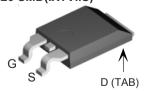


TO-268 (IXTT)





PLUS220 SMD(IXTV..S)



G = Gate S = Source D = Drain TAB = Drain

## **Features**

- <sup>1</sup> International standard packages
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect

# IXTH 36N50P IXTQ 36N50P IXTT 36N50P IXTV36N50P IXTV 36N50PS

Symbol		Characteristic Values = 25° C unless otherwise specified)	
	Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 20 \text{ V}; I_{D} = 0.5 I_{D25}, \text{ pulse test}$ 23	36	S
C <sub>iss</sub>		5500	pF
C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	510	pF
C <sub>rss</sub>		40	pF
t <sub>d(on)</sub>		25	ns
t <sub>r</sub>	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = I_{D25}$	27	ns
t <sub>d(off)</sub>	$R_{_{G}} = 3 \Omega (External)$	75	ns
t <sub>f</sub>		21	ns
$\mathbf{Q}_{g(on)}$		85	nC
$Q_{gs}$	$V_{GS}^{}$ = 10 V, $V_{DS}^{}$ = 0.5 $V_{DSS}^{}$ , $I_{D}^{}$ = 0.5 $I_{D25}^{}$	30	nC
$\mathbf{Q}_{gd}$		31	nC
R <sub>thJC</sub>			0.23 ° C/W
R <sub>thcs</sub>	(TO-247 and TO-3P) (PLUS220)	0.21 0.21	° C/W ° C/W

### Source-Drain Diode

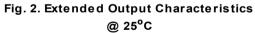
### **Characteristic Values**

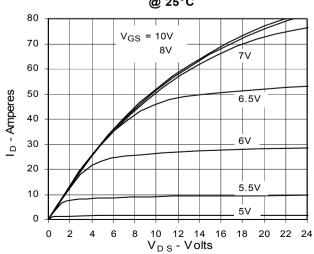
(T<sub>1</sub> = 25° C unless otherwise specified)

Symbol	Test Conditions	Min.	Тур.	Max.	,
I <sub>s</sub>	V <sub>GS</sub> = 0 V			36	Α
I <sub>sm</sub>	Repetitive			108	Α
V <sub>SD</sub>	$I_F = I_S, V_{GS} = 0 \text{ V},$ Pulse test, t ≤300 µs, duty cycle d≤ 2 %			1.5	V
t <sub>rr</sub>	$I_F = 25 \text{ A}, -\text{di/dt} = 100 \text{ A/}\mu\text{s}$ $V_R = 100 \text{ V}, V_{GS} = 0 \text{ V}$		400		ns

## **Characteristic Curves**

Fig. 1. Output Characteristics @ 25°C 36  $V_{GS} = 10V$ 32 8V 28 7V 24 I<sub>D</sub> - Amperes 6V 20 16 12 5.5V 8 4 5V 0 2 6 0 3 5 V<sub>DS</sub> - Volts





IXYS reserves the right to change limits, test conditions, and dimensions.

Fig. 3. Output Characteristics @ 125°C

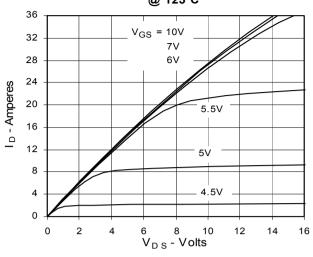


Fig. 5. R<sub>DS(on)</sub> Normalized to

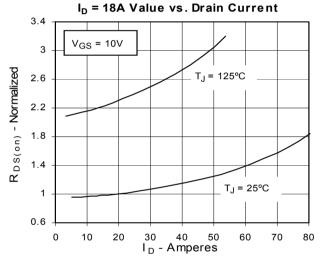


Fig. 7. Input Admittance

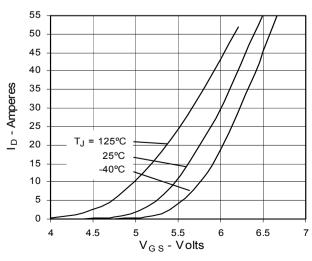


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 18A$ Value vs. Junction Temperature

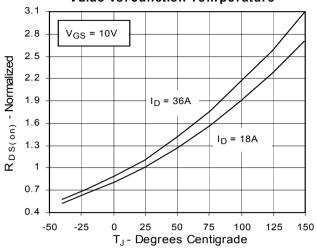


Fig. 6. Drain Current vs. Case

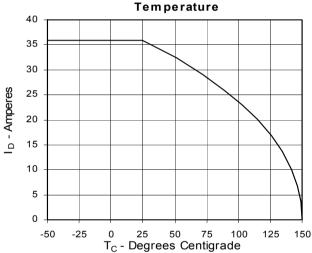


Fig. 8. Transconductance

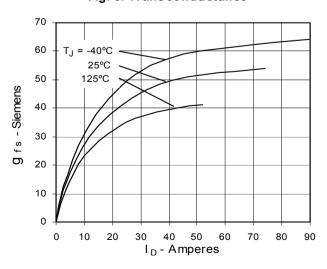




Fig. 9. Source Current vs. Source-To-Drain Voltage

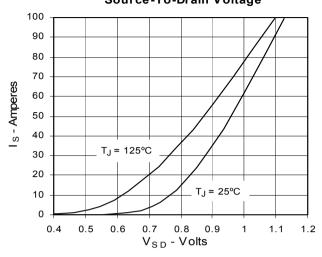


Fig. 10. Gate Charge

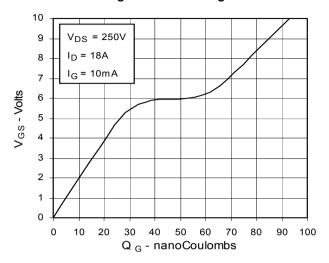


Fig. 11. Capacitance

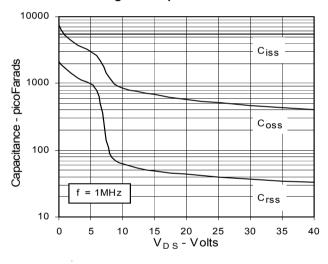


Fig. 12. Forward-Bias Safe Operating Area

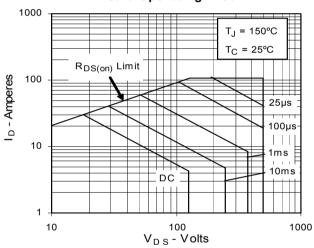
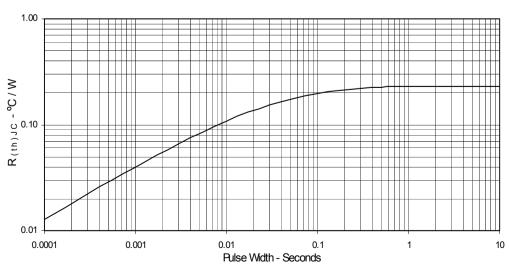


Fig. 13. Maximum Transient Thermal Resistance

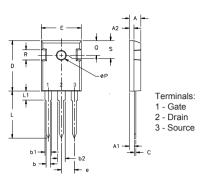


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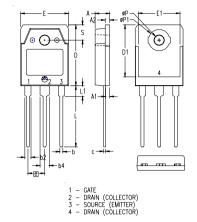
## **IXTH 36N50P IXTQ 36N50P IXTT 36N50P IXTV 36N50P IXTV 36N50PS**

## TO-247 AD (IXTH) Outline



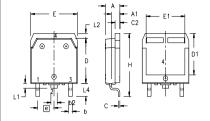
Dim.	Milli	imeter	Inc	hes
	Min.	Max.	Min.	Max.
Α	4.7	5.3	.185	.209
$A_1$	2.2	2.54	.087	.102
A <sub>2</sub>	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b,	1.65	2.13	.065	.084
b <sub>2</sub>	2.87	3.12	.113	.123
С	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
е	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
ØP	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	242	BSC

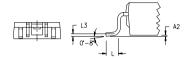
## TO-3P (IXTQ) Outline



SYM	INCH	4ES	MILLIN	1ETERS
SIM	MIN	MAX	MIN	MAX
Α	.185	.193	4.70	4.90
A1	.051	.059	1.30	1.50
A2	.057	.065	1.45	1.65
ь	.035	.045	0.90	1.15
b2	.075	.087	1.90	2.20
b4	.114	.126	2.90	3.20
С	.022	.031	0.55	0.80
D	.780	.799	19.80	20.30
D1	.665	.677	16.90	17.20
E	.610	.622	15.50	15.80
E1	.531	.539	13.50	13.70
е	.215	BSC	5.45	BSC
L	.779	.795	19.80	20.20
L1	.134	.142	3.40	3.60
ØΡ	.126	.134	3.20	3.40
øP1	.272	.280	6.90	7.10
S	.193	.201	4.90	5.10

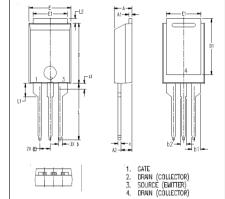
## TO-268 (IXTT) Outline





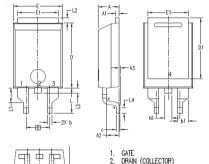
SYM	INCH	IES .	MILLIN	METERS
2114	MIN	MAX	MIN	MAX
Α	.193	.201	4.90	5.10
A1	.106	.114	2.70	2.90
A2	.001	.010	0.02	0.25
Ь	.045	.057	1.15	1.45
b2	.075	.083	1.90	2.10
С	.016	.026	0.40	0.65
C2	.057	.063	1.45	1.60
D	.543	.551	13.80	14.00
D1	.488	.500	12.40	12.70
E	.624	.632	15.85	16.05
E1	.524	.535	13.30	13.60
е	.215	BSC	5.45	BSC
Н	.736	.752	18.70	19.10
L	.094	.106	2.40	2.70
L1	.047	.055	1.20	1.40
L2	.039	.045	1.00	1.15
L3	.010 BSC		0.25	BSC
L4	.150	.161	3.80	4.10

## PLUS220 (IXTV) Outline



SYM	INC	ES	MILLIMETE	
2114	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.028	.035	0.70	0.90
A2	.098	.118	2.50	3.00
Ь	.035	.047	0.90	1.20
Ь1	.080	.095	2.03	2.41
b2	.054	.064	1.37	1.63
С	.028	.035	0.70	0.90
D	.551	.591	14.00	15.00
D1	.512	.539	13.00	13.70
E	.394	.433	10.00	11.00
E1	.331	.346	8.40	8.80
е	.100	DBSC	2.54 BSC	
L	.512	.551	13.00	14.00
L1	.118	.138	3,00	3,50
L2	.035	.051	0.90	1.30
1.3	.047	.059	1,20	1.50

## PLUS220SMD (IXTV\_S) Outline





SYM	INCH	HES	MILLI	METER
2114	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.028	.035	0.70	0.90
A2	.098	.118	2.50	3.00
A3	.000	.010	0.00	0.25
Ь	.035	.047	0.90	1.20
ь1	.080	.095	2.03	2.41
b2	.054	.064	1.37	1.63
С	.028	.035	0.70	0.90
D	.551	.591	14.00	15.00
D1	.512	.539	13.00	13.70
E	.394	.433	10.00	11.00
E1	.331	.346	8.40	8.80
е	.20	OB2C	5.08	BZC
L	.209	.228	5.30	5.80
L1	.118	.138	3.00	3.50
L2	.035	.051	0.90	1.30
L3	.047	.059	1.20	1.50
L4	.039	.059	1.00	1.50

